Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.505 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.562 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

10.0 reverse gate to source breakdown voltage

**Current Rating Per Characteristic:** 

6.40 amperes source cutoff current absolute

**Power Rating Per Characteristic:** 

40.0 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

120.0 degrees celsius case

**Special Features:** 

Junction pattern arrangement: pnpn

**Thread Series Designator:** 

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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